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Team Nexperia



PMEG4030EP

3 A low V_F MEGA Schottky barrier rectifier Rev. 01 — 7 August 2009

Product data sheet

Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD128 small and flat lead Surface-Mounted Device (SMD) plastic package.

1.2 Features

- Average forward current: I_{F(AV)} ≤ 3 A
- Reverse voltage: V_R ≤ 40 V
- Low forward voltage
- High power capability due to clip-bond technology
- AEC-Q101 qualified
- Small and flat lead SMD plastic package

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 1. Quick reference data $T_i = 25 \,^{\circ}C$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--|-----------------|--|--------------|-----|-----|------|
| I _{F(AV)} average forward current | | square wave; $\delta = 0.5$; $f = 20 \text{ kHz}$ | | | | |
| | | T _{amb} ≤ 65 °C | <u>[1]</u> _ | - | 3 | Α |
| | | T _{sp} ≤ 140 °C | - | - | 3 | Α |
| V_R | reverse voltage | | - | - | 40 | V |
| V _F | forward voltage | $I_F = 3 A$ | - | 430 | 490 | mV |
| I _R | reverse current | V _R = 40 V | - | 35 | 200 | μΑ |
| | | | | | | |

^[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.



2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline | Graphic symbol |
|-----|-------------|--------------------|----------------|
| 1 | cathode | [1] | . [4] |
| 2 | anode | 1 2 | 1 1 2 |
| | | <u> </u> | sym001 |

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|--|---------|
| | Name | Description | Version |
| PMEG4030EP | - | plastic surface-mounted package; 2 leads | SOD128 |

4. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PMEG4030EP | AE |

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|--------------------|-------------------------------------|---|--------------|------|------|
| V_R | reverse voltage | T _j = 25 °C | - | 40 | V |
| I _{F(AV)} | average forward current | square wave; $\delta = 0.5$; f = 20 kHz | | | |
| | | $T_{amb} \le 65 ^{\circ}C$ | <u>[1]</u> - | 3 | Α |
| | | $T_{sp} \le 140 ^{\circ}C$ | - | 3 | Α |
| I _{FSM} | non-repetitive peak forward current | square wave; $t_p = 8 \text{ ms}$ | [2] _ | 50 | Α |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [3][4] | 625 | mW |
| | | | [3][5] | 1050 | mW |
| | | | [3][1] | 2100 | mW |



Table 5. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|----------------------|------------|-----|------|------|
| T _j | junction temperature | | - | 150 | °C |
| T_{amb} | ambient temperature | | -55 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

- [1] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- [2] $T_i = 25$ °C prior to surge.
- [3] Reflow soldering is the only recommended soldering method.
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [5] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

6. Thermal characteristics

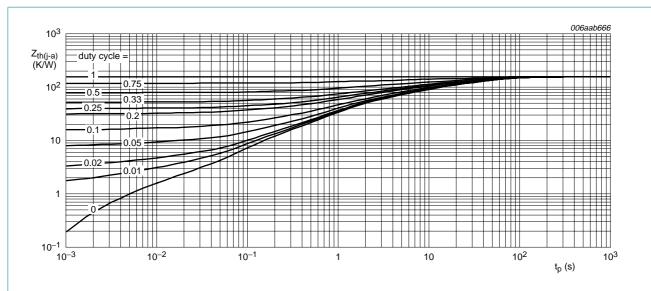
Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------|--|-------------|--------------|-----|-----|------|
| -un(j-a) | thermal resistance from | in free air | [1][2] | | | |
| | junction to ambient | | [3] | - | 200 | K/W |
| | | | <u>[4]</u> _ | - | 120 | K/W |
| | | | [5] | - | 60 | K/W |
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | | <u>[6]</u> _ | - | 12 | K/W |

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.
- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- [5] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- 6] Soldering point of cathode tab.

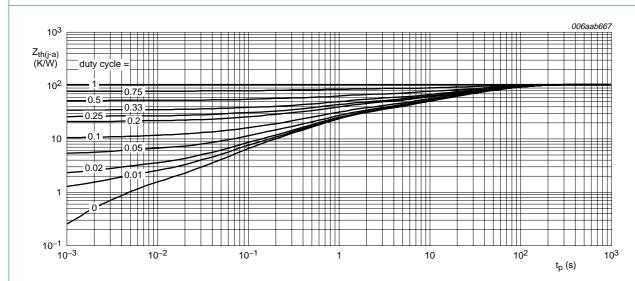
4 of 13

3 A low V_F MEGA Schottky barrier rectifier



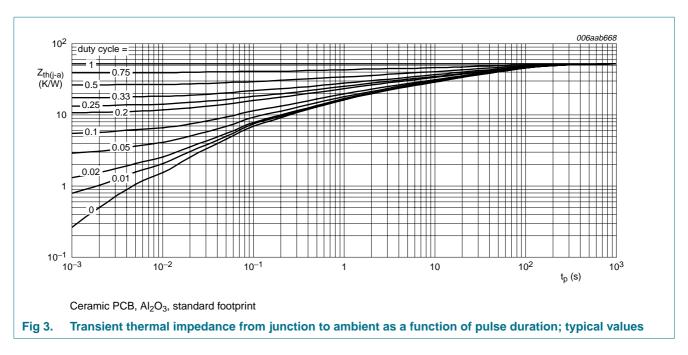
FR4 PCB, standard footprint

Fig 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for cathode 1 cm²

Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



7. Characteristics

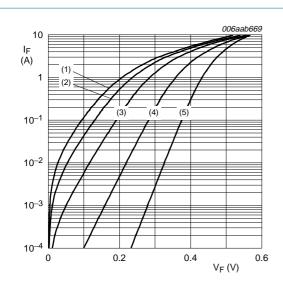
 Table 7.
 Characteristics

 $T_i = 25 \,^{\circ}C$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------|-------------------|----------------------|-----|-----|-----|------|
| V_{F} | forward voltage | $I_F = 0.1 A$ | - | 285 | 320 | mV |
| | | I _F = 1 A | - | 360 | 420 | mV |
| | | I _F = 3 A | - | 430 | 490 | mV |
| I_R | reverse current | $V_R = 10 V$ | - | 7 | - | μΑ |
| | $V_R = 40 V$ | - | 35 | 200 | μΑ | |
| C_d | diode capacitance | f = 1 MHz | | | | |
| | | $V_R = 1 V$ | - | 350 | - | pF |
| | | $V_R = 10 V$ | - | 140 | - | pF |
| | | | | | | |

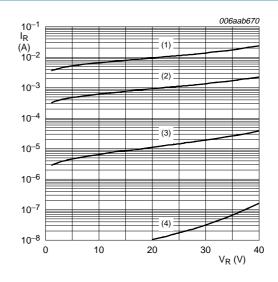
6 of 13

3 A low V_F MEGA Schottky barrier rectifier



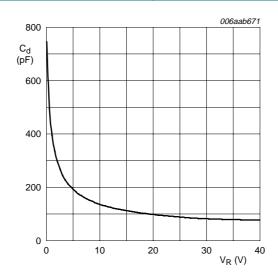
- (1) $T_j = 150 \,^{\circ}\text{C}$
- (2) $T_i = 125 \, ^{\circ}C$
- (3) $T_i = 85 \,^{\circ}C$
- (4) $T_j = 25 \, ^{\circ}C$
- (5) $T_j = -40 \, ^{\circ}C$

Fig 4. Forward current as a function of forward voltage; typical values



- (1) T_j = 125 °C
- (2) $T_j = 85 \,^{\circ}C$
- (3) $T_j = 25$ °C
- (4) $T_j = -40 \, ^{\circ}C$

Fig 5. Reverse current as a function of reverse voltage; typical values

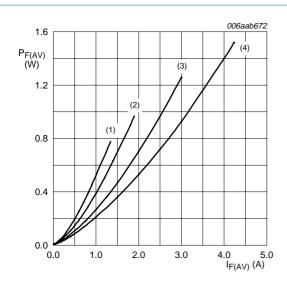


f = 1 MHz; T_{amb} = 25 °C

Product data sheet

Fig 6. Diode capacitance as a function of reverse voltage; typical values

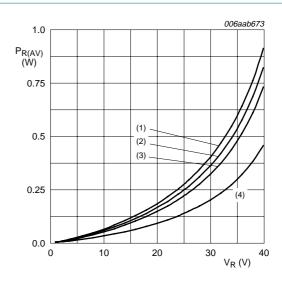
Rev. 01 — 7 August 2009



T_j = 150 °C

- (1) $\delta = 0.1$
- (2) $\delta = 0.2$
- (3) $\delta = 0.5$
- (4) $\delta = 1$

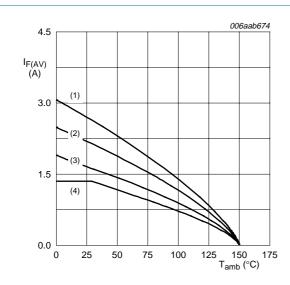
Average forward power dissipation as a Fig 7. function of average forward current; typical values



T_i = 125 °C

- (1) $\delta = 1$
- (2) $\delta = 0.9$
- (3) $\delta = 0.8$
- (4) $\delta = 0.5$

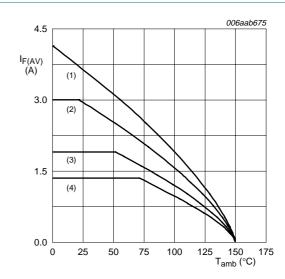
Fig 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; f = 20 kHz
- (3) $\delta = 0.2$; f = 20 kHz
- (4) $\delta = 0.1$; f = 20 kHz

Average forward current as a function of Fig 9. ambient temperature; typical values



FR4 PCB, mounting pad for cathode 1 cm²

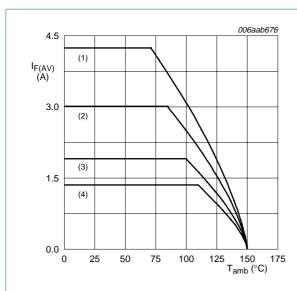
$$T_j = 150 \, ^{\circ}C$$

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; f = 20 kHz
- (3) $\delta = 0.2$; f = 20 kHz
- (4) $\delta = 0.1$; f = 20 kHz

Fig 10. Average forward current as a function of ambient temperature; typical values

7 of 13

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Ceramic PCB, Al_2O_3 , standard footprint

T_i = 150 °C

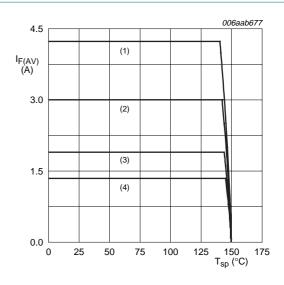
(1) $\delta = 1$; DC

(2) $\delta = 0.5$; f = 20 kHz

(3) $\delta = 0.2$; f = 20 kHz

(4) $\delta = 0.1$; f = 20 kHz

Fig 11. Average forward current as a function of ambient temperature; typical values



 $T_j = 150 \, ^{\circ}C$

(1) $\delta = 1$; DC

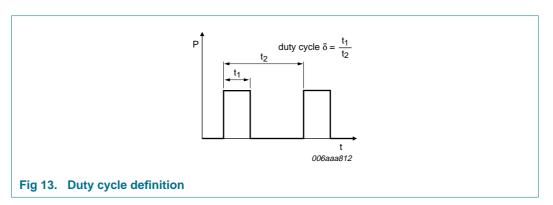
(2) $\delta = 0.5$; f = 20 kHz

(3) $\delta = 0.2$; f = 20 kHz

(4) $\delta = 0.1$; f = 20 kHz

Fig 12. Average forward current as a function of solder point temperature; typical values

8. Test information



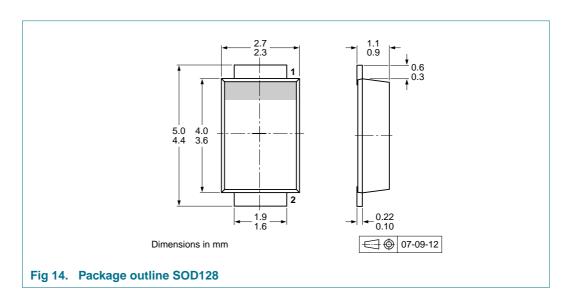
The current ratings for the typical waveforms as shown in Figure 9, 10, 11 and 12 are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current,

 $I_{RMS}=I_{F(AV)}$ at DC, and $I_{RMS}=I_{M} imes\sqrt{\delta}$ with I_{RMS} defined as RMS current.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

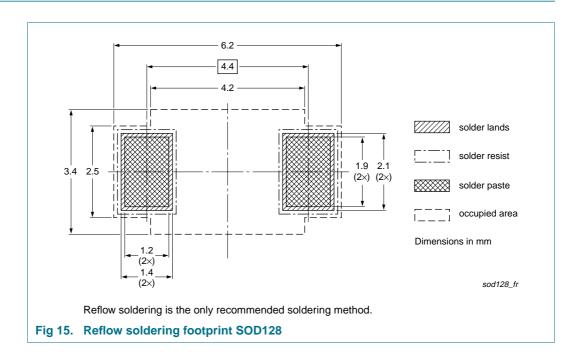
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | mber Package Description | | Packing quantity |
|-------------|--------------------------|---------------------------------|------------------|
| | | | 3000 |
| PMEG4030EP | SOD128 | 4 mm pitch, 12 mm tape and reel | -115 |

^[1] For further information and the availability of packing methods, see Section 14.

11. Soldering





12. Revision history

Table 9. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|--------------|--------------|--------------------|---------------|------------|
| PMEG4030EP_1 | 20090807 | Product data sheet | - | - |

13. Legal information

13.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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- [2] The term 'short data sheet' is explained in section "Definitions"
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15. Contents

| 1 | Product profile |
|------|---------------------------|
| 1.1 | General description |
| 1.2 | Features |
| 1.3 | Applications 1 |
| 1.4 | Quick reference data |
| 2 | Pinning information 2 |
| 3 | Ordering information |
| 4 | Marking 2 |
| 5 | Limiting values 2 |
| 6 | Thermal characteristics 3 |
| 7 | Characteristics 5 |
| 8 | Test information |
| 8.1 | Quality information 9 |
| 9 | Package outline 9 |
| 10 | Packing information 10 |
| 11 | Soldering 10 |
| 12 | Revision history |
| 13 | Legal information |
| 13.1 | Data sheet status |
| 13.2 | Definitions |
| 13.3 | Disclaimers |
| 13.4 | Trademarks12 |
| 14 | Contact information 12 |
| 15 | Contents 13 |

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